

## **Brief Description**

The ZSSC3018 is a sensor signal conditioner (SSC) integrated circuit for high-accuracy amplification and analog-to-digital conversion of differential or pseudo-differential input signals. Designed for high-resolution sensor module applications, the ZSSC3018 can perform offset, span, and 1st and 2nd order temperature compensation of the measured signal. Developed for correction of resistive bridge or absolute voltage sensors, it can also provide a corrected temperature output measured with an internal sensor.

The measured and corrected sensor values are provided at the digital output pins, which can be configured as I²C (≤3.4MHz) or SPI (≤10MHz). Digital compensation of signal offset, sensitivity, temperature, and non-linearity is accomplished via a 26-bit internal digital signal processor (DSP) running a correction algorithm. Calibration coefficients are stored on-chip in a highly reliable, non-volatile, multiple-time programmable (MTP) memory. Programming the ZSSC3018 is simple via the serial interface. The interface is used for the PC-controlled calibration procedure, which programs the set of calibration coefficients in memory. The ZSSC3018 provides accelerated signal processing, increased resolution, and improved noise immunity in order to support high-speed control, safety, and real-time sensing applications with the highest requirements for energy efficiency.

### **Features**

- Flexible, programmable analog front-end design; up to 18-bit analog-to-digital converter (ADC)
- Fully programmable gain amplifier with gain range from 6.6 to 216 (linear)
- Internal auto-compensated temperature sensor
- Digital compensation of individual sensor offset; 1st and 2nd order digital compensation of sensor gain as well as of 1st and 2nd order temperature gain and offset drift
- Programmable interrupt operation
- High-speed sensing: e.g., 16-bit conditioned sensor signal measurement rate >500s<sup>-1</sup>
- Typical sensor system can achieve an accuracy of better than ±0.10% FSO\* @ -40 to 125°C

#### **Benefits**

- Integrated 26-bit calibration math DSP
- Fully corrected signal at digital output
- Layout customized for die-die bonding with sensor for highdensity chip-on-board assembly
- One-pass calibration minimizes calibration costs
- No external trimming, filter, or buffering components required
- Highly integrated CMOS design
- Integrated reprogrammable non-volatile memory
- Excellent for low-voltage and low-power battery applications
- Optimized for operation in calibrated resistive sensor (e.g., pressure) or calibrated absolute voltage sensor (e.g., thermopile) modules

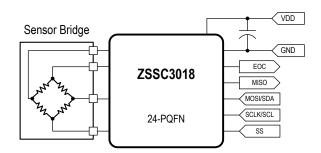
# **Physical Characteristics**

- Supply voltage range: 1.68V to 3.6V
- Current consumption: ~1.0mA (typical) in operating mode
- Sleep Mode current: 50nA (typical) at ≤125°C; 20nA (typical) at ≤85°C
- Temperature resolution: <0.003K/LSB</li>
- Best-in-class energy-efficiency:

with 16-bit resolution: <140pJ/step with 18-bit resolution: <50pJ/step

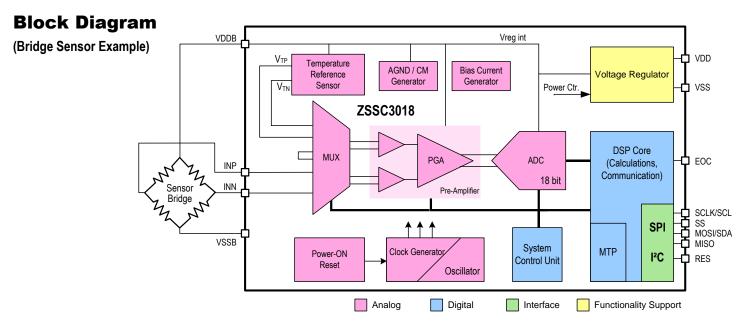
- Operation temperature: –40°C to +125°C
- Delivery options: die or 24-PQFN (4 x 4 mm) package

# **ZSSC3018 Application Example**



<sup>\*</sup> FSO = Full Scale Output.





## **Applications**

- Barometric altitude measurement for portable navigation or emergency call systems
- Altitude measurement for car navigation
- Weather forecast

- Fan control
- Industrial, pneumatic, and liquid pressure
- High-resolution temperature measurements
- Object-temperature radiation (via thermopile)



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## 1. IC Characteristics

# 1.1 Absolute Maximum Ratings

Note: The absolute maximum ratings are stress ratings only. The ZSSC3018 might not function or be operable above the recommended operating conditions. Stresses exceeding the absolute maximum ratings might also damage the device. In addition, extended exposure to stresses above the recommended operating conditions might affect device reliability. Renesas does not recommend designing to the "Absolute Maximum Ratings."

**Table 1.1 Absolute Maximum Ratings** 

PARAMETER	SYMBOL	Min	TYP	MAX	UNITS
Voltage Reference	Vss	0	-	0	V
Analog Supply Voltage	$V_{DD}$	-0.4	-	3.63	V
Voltage at all Analog and Digital IO Pins	$V_{A\_IO}, V_{D\_IO}$	-0.5	-	V <sub>DD</sub> +0.5	V
Input Current into any Pin except RES, TEST1, TEST2, TEST3, TEST4, TEST5, and SS [a], [b]	I <sub>IN</sub>	-100	1	100	mA
Electrostatic Discharge Tolerance – Human Body Model (HBM1) [c]	V <sub>HBM1</sub>	4000	-	_	V
Storage Temperature	T <sub>STOR</sub>	-50	_	130	°C

<sup>[</sup>a] Latch-up current limit for RES, TEST1, TEST2, TEST3, TEST4, TEST5, and SS: ±70mA.

## 1.2 Operating Conditions

Note: The reference for all voltages is Vss.

**Table 1.2 Operating Conditions** 

PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT
Supply Voltage	$V_{DD}$	1.68	_	3.6	V
VDD Rise Time	t <sub>VDD</sub>	_	_	200	μs
Dridge Current [a]	1	-	_	1.8	m Λ
Bridge Current [a]	IVDDB	_	_	16.5	mA
Operation Temperature Range	T <sub>AMB</sub>	-40	_	125	°C
External (Parasitic) Capacitance between VDDB and VSS	CL	0.01	-	50	nF

<sup>[</sup>a] Power supply rejection is reduced if a current in the range of 16.5mA > I<sub>VDDB</sub> > 1.8mA is drawn out of VDDB.

A dynamic power-on-reset circuit is implemented in order to achieve the minimum current consumption in Sleep Mode. The VDD low level, the subsequent rise time, and the VDD rising slope must meet the requirements in Table 1.3 to guarantee an overall IC reset: lower VDD low levels allow slower rising of the subsequent on-ramp of VDD. Other combinations might also be possible. For example, the reset trigger can be influenced by increasing the power-down time and lowering the VDD rising slope requirement. Alternatively, the RES pin can be connected and used to control safe resetting of the IC. RES is low-active – a VDD-VSS-VDD transition at the RES pin leads to a complete ZSSC3018 reset.

<sup>[</sup>b] Latch-up resistance; reference for pin is 0V.

<sup>[</sup>c] HBM1: C = 100pF charged to V<sub>HBM1</sub> with resistor R = 1.5kΩ in series based on MIL 883, Method 3015.7. ESD protection referring to the Human Body Model is tested with devices in ceramic dual in-line packages (CDIP) during product qualification.



Table 1.3 Requirements for VDD Power-on Reset (POR)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT
Power Down Time (duration of VDD Low Level)	t <sub>SPIKE</sub>	3	-	-	μs
VDD Low Level	VDD <sub>LOW</sub>	0	-	0.2	V
VDD Rising Slope	SR <sub>VDD</sub>	10	1	1	V/ms

# 1.3 Electrical Parameters

All parameter values are valid only under the specified operating conditions. All voltages are referenced to Vss.

## **Table 1.4 Electrical Parameters**

Note: See important table notes at the end of the table.

Parameter	Symbol	Conditions/Comments	Min	Тур	Max	Unit	
Supply							
External Sensor Supply Voltage, ADC Reference Voltage	V <sub>DDB</sub>	Internally generated	1.60	1.68	1.75	V	
		Active State, average	-	1050	1500	μA	
Current Consumption	I <sub>VDD</sub>	Sleep Mode, idle current, ≤ 85°C	-	20	250	n A	
		Sleep Mode, idle current, ≤ 125°C	-	50	750	nA	
Power Supply Rejection	505	V <sub>DD</sub> = 1.8V	17	60	88	dB	
20·log <sub>10</sub> (V <sub>DD</sub> /V <sub>DDB</sub> ) (see section 1.4)	PSR <sub>VDD</sub>	V <sub>DD</sub> = 2V	32	65	91	dB	
Analog-to-Digital Converter (AD	C, A2D)						
Resolution	r <sub>ADC</sub>		12	-	18	Bit	
ADC Clock Frequency	f <sub>ADC</sub>	Internal ADC clock	0.9	1	1.1	MHz	
Conversion Date	f	Conversions per second for single 18- bit external sensor A2D conversion (w/o AZ)	-	-	1.1	kHz	
Conversion Rate	f <sub>S,raw</sub>	Conversions per second for single 16- bit temperature sensor A2D conversion (w/o AZ)	_	-	2.3	kHz	
Amplifier		<u>.</u>					
Gain	G <sub>AMP</sub>	64 steps	6.6	-	216		
Gain Error	G <sub>ERR</sub>	Referenced to nominal gain	-2.5		2.5	%	

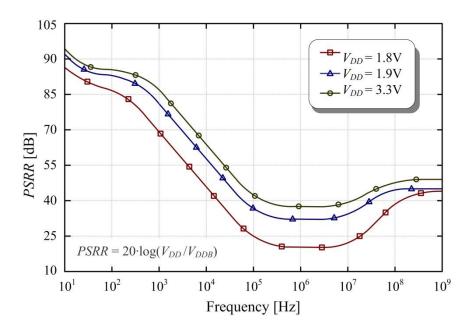


Parameter	Symbol	Conditions/Comments	Min	Тур	Max	Unit
Sensor Signal Conditioning Per	formance					•
		Accuracy error for ideally linear (in temperature and measurand) sensor	_	_	0.01	%FSO
Conversion Rate, 18-Bit Output with Sensor Signal Conditioning	f <sub>s, ssc</sub>	Conversion per second for fully corrected 18-bit measurement	_	270	300	Hz
Input						
Input Voltage Range	V <sub>INP</sub> , V <sub>INN</sub>	Input voltage range at INP and INN	0.65	-	1.05	V
External Sensor Bridge Resistance	$R_{BR}$	Full power supply disturbance rejection (PSRR) capabilities	1	10	50	kΩ
Resistance		Reduced PSRR, but full functionality	100	-	999	Ω
Power-Up						
Start-up Time	t <sub>STA1</sub>	V <sub>DD</sub> ramp up to interface communication (see section 3.1)	ı	ı	1	ms
otalit up rimie	t <sub>STA2</sub>	V <sub>DD</sub> ramp up to analog operation	_	-	2.5	ms
Wake-up Time	t <sub>WUP1</sub>	Sleep to Active State interface communication	_	-	0.5	ms
	t <sub>WUP2</sub>	Sleep to Active State analog operation	_	-	2	ms
Oscillator			•		•	
Internal Oscillator Frequency	f <sub>CLK</sub>		3.6	4	4.4	MHz
Internal Temperature Sensor						
Temperature Resolution		-40°C to +125°C (Temperature resolution is 16 bits)	ı	0.003	_	K/LSB
Interface and Memory						
SPI Clock Frequency f <sub>C,SPI</sub>		Maximum capacitance at MISO line: 40pF @ V <sub>DD</sub> =1.8V	_	1	10	MHz
I <sup>2</sup> C Clock Frequency	<sup>2</sup> C Clock Frequency f <sub>C,I2C</sub>		-	-	3.4	MHz
Program Time t <sub>PROG</sub> MTP program register		MTP programming time per 16-bit register	_	5	16	ms
Endurance	n <sub>MTP</sub>	Number of reprogramming cycles	1000	10000	-	numeric
Data Retention	t <sub>RET_MTP</sub>	1000h @ 125°C	10	-	-	years

<sup>[</sup>a] Percentage referenced to maximum full-scale output (FSO); e.g. for 18-bit measurements:  $Err_{A,IC}$  [%FSO] =  $100 \cdot MAX\{|ADC_{meas} - ADC_{ideal}|\} / 2^{18}$ .



# 1.4 Power Supply Rejection Ratio (RSRR) versus Frequency





# 2. Circuit Description

# 2.1 Brief Description

The ZSSC3018 provides a highly accurate amplification of bridge sensor signals. The compensation of sensor offset, sensitivity, temperature drift, and non-linearity is accomplished via a 26-bit DSP core running a correction algorithm with calibration coefficients stored in a non-volatile memory. The ZSSC3018 can be configured for a wide range of resistive bridge sensor types and for absolute voltage-source sensors. A digital interface (SPI or I<sup>2</sup>C) enables communication. The ZSSC3018 supports two operational modes: Normal Mode and Command Mode. Normal Mode is the standard operating mode. Typically in Normal Mode, the ZSSC3018 wakes up from Sleep Mode (low power), runs a measurement in Active State, and automatically returns to the Sleep Mode. (See section 3.3 for details on operational modes.)

## 2.2 Signal Flow and Block Diagram

See Figure 2.1 and Figure 2.2 for the ZSSC3018 block diagram for different input sensors. The sensor bridge supply V<sub>DDB</sub> and the power supply for analog circuitry are provided by a voltage regulator, which is optimized for power supply disturbance rejection (PSRR). See section 1.4 for a graph of PSRR versus frequency. To improve noise suppression, the digital blocks are powered by a separate voltage regulator. A power supervision circuit monitors all supply voltages and generates appropriate reset signals for initializing the digital blocks.

The System Control Unit controls the analog circuitry to perform the three measurement types: external sensor, temperature, and offset measurement. The multiplexer selects the signal input to the amplifier, which can be the external signals from the input pins INP and INN or the internal temperature reference sensor signals. A full measurement request will trigger an automatic sequence of all measurement types and all input signals.

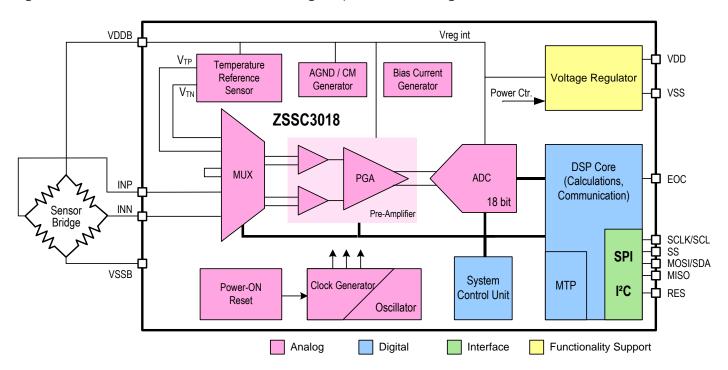
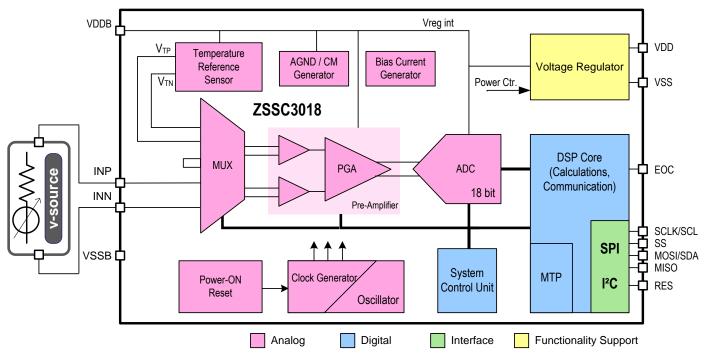


Figure 2.1 ZSSC3018 Functional Block Diagram, Resistive-Bridge-Sensor



Figure 2.2 ZSSC3018 Functional Block Diagram, Voltage-Source-Sensor



The amplifier consists of two stages with programmable gain values.

The ZSSC3018 employs a programmable analog-to-digital converter (ADC) optimized for conversion speed and noise suppression. The programmable resolution from 12 to 18 bits provides flexibility for adapting the conversion characteristics. To improve power supply noise suppression, the ADC uses the bridge supply  $V_{\text{DDB}}$  as its reference voltage leading to a ratiometric measurement topology if the external sensor is a bridge-type element.

The remaining IC-internal offset and the sensor element offset, i.e., the overall system offset for the amplifier and ADC, can be canceled by means of an offset and auto-zero measurement, respectively.

The DSP accomplishes the auto-zero, span, and 1<sup>st</sup> and 2<sup>nd</sup> order temperature compensation of the measured external sensor signal. The correction coefficients are stored in the MTP memory.

The ZSSC3018 supports SPI and I<sup>2</sup>C interface communication for controlling the ZSSC3018, configuration, and measurement result output.



# 2.3 Analog Front End

## 2.3.1 Amplifier

The amplifier has a fully differential architecture and consists of two stages. The amplification of each stage and the external sensor gain polarity are programmable via settings in the Measurement Configuration Registers  $SM\_config1$  and  $SM\_config2$  (addresses  $12_{HEX}$  and  $16_{HEX}$ ; see section 3.6.2) in the MTP memory (see section 2.4.2). Only one of these two possible configurations is used for measurements. The default configuration is  $SM\_config1$ . Alternately,  $SM\_config2$  can be implemented by sending a command to select this configuration for the measurement (see section 3.5.1). The term  $SM\_config1$  is used for general register content and functionality explanations for both,  $SM\_config1$  and  $SM\_config2$ , as the registers' bit assignments are exactly the same for both registers.

The first 6 bits of SM\_config are the programmable gain settings Gain\_stage1 and Gain\_stage2. The options for the programmable gain settings are listed in Table 2.1 and Table 2.2.

Table 2.1 Amplifier Gain: Stage 1

Gain_stage1					
SM_config Bit G2	SM_config Bit G1	SM_config Bit G0	Gain <sub>amp1</sub>		
0	0	0	6		
0	0	1	12		
0	1	0	20		
0	1	1	30		
1	0	0	40		
1	0	1	60		
1	1	0	80		
1	1	1	120		

Table 2.2 Amplifier Gain: Stage 2

Gain_stage2					
SM_config Bit G5	SM_config Bit G4	SM_config Bit G3	Gain <sub>amp2</sub>		
0	0	0	1.1		
0	0	1	1.2		
0	1	0	1.3		
0	1	1	1.4		
1	0	0	1.5		
1	0	1	1.6		
1	1	0	1.7		
1	1	1	1.8		



If needed, the polarity of the sensor bridge gain can be reversed by setting the *Gain\_polarity* bit, which is bit 6 in the *SM\_config* register (see section 3.6.2). Changing the gain polarity is achieved by inverting the chopper clock. Table 2.3 gives the settings for the *Gain\_polarity* bit. This feature enables applying a sensor to the ZSSC3018 with swapped input signals at INN and INP; e.g., to avoid crossing wires for the final sensor module's assembly.

**Table 2.3 Gain Polarity** 

Gain_polarity (SM_config Bit 6)	Gain	Setting Description
0	+1	No polarity change.
1	-1	Gain polarity is inverted.

### 2.3.2 Analog-to-Digital Converter

An analog-to-digital converter (ADC) is used to digitize the amplifier signal. To allow optimizing the trade-off between conversion time and resolution, the resolution can be programmed from 12-bit to 18-bit (see *Adc\_bits*, *SM\_config* register; section 3.6.2). The ADC processes differential input signals.

Table 2.4 ADC Conversion Times for a Single A2D Conversion

Resolution [Bits]	Conversion Time in µs (typical)
12	140
13	185
14	250
15	335
16	470
17	640
18	890

The ADC can perform an offset shift in order to adapt input signals with offsets to the ADC input range. The shift feature is enabled by setting  $SM\_config$  registers' bit[15] = 1 ( $Shift\_method$  = 1). The respective analog offset shift can be set up with bits[14:12], the Offset bit field in  $SM\_config$ .

**Note:** The offset shift causes the ADC to perform an additional amplification of the ADC's input signal by a factor of 2. This must be considered for a correct analog sensor setup using the pre-amplifier's gain, the ADC offset shift, and the potential ADC gain.

The overall analog amplification  $Gain_{total} = Gain_{amp1} * Gain_{amp2} * Gain_{ADC}$  can be determined for the following options:

• If no offset shift is selected, i.e. Shift\_method = 0 and Offset = 000 in SM\_config:

$$Gain_{total} = Gain_{amp1} * Gain_{amp2} * 1$$

If ADC offset shift is selected, i.e. Shift\_method = 1 and Offset ≠ 000 in SM\_config:

$$Gain_{total} = Gain_{amp1} * Gain_{amp2} * 2$$



Table 2.5 ADC Offset Shift

	Offset Shift in ADC							
SM_config Bit 15 (Shift_method)	Offset: SM_config Bit 14	Offset: SM_config Bit 13	Offset: SM_config Bit 12	Gain <sub>ADC</sub>	ADC Offset Shift of Input Signal as a Percent of Full Scale			
0	0	0	0	1	0%			
1	0	0	0	2	0%			
1	0	0	1	2	6.75%			
1	0	1	0	2	12.50%			
1	0	1	1	2	19.25%			
1	1	0	0	2	25.00%			
1	1	0	1	2	31.75%			
1	1	1	0	2	38.50%			
1	1	1	1	2	43.25%			

**Important:** If the required configuration is no offset shift and no additional gain factor (and therefore  $Gain_{ADC} = 1$ ), then the only valid settings are  $Shift\_method = 0$  and Offset = 000 in  $SM\_config$ . Any other setup using  $Shift\_method = 0$  combined with  $Offset \neq 000$  leads to erroneous analog setups.

The setting for ADC resolution for the external sensor (bridge or voltage-source sensor) affects the typical measurement duration and noise performance as shown in Table 2.6 for the example of a bridge sensor measurement using the "Measure" command (AA<sub>HEX</sub>; see section 3.4.1). See section 3.2 for definitions of measurement types AZSM, SM, AZTM, and TM.

Table 2.6 Typical Conversion Times versus Noise Performance with Full Sensor Signal Conditioning for Measurement Including AZSM, SM, AZTM, and TM (Bridge-Type Sensor)

Note: See important table notes at the end of this table.

ADC Resolution: Internal Temperature Sensor	ADC Resolution: External Sensor	Typical Measurement Duration [a], MEASURE, (AA <sub>HEX</sub> ) [ms]	Typical 3-Sigma Noise for SSC-Corrected Output <sup>[b]</sup> [counts]
16	12	2.2	2.4
16	13	2.3	2.5
16	14	2.4	3.0
16	15	2.6	4.4



ADC Resolution: Internal Temperature Sensor	ADC Resolution: External Sensor	Typical Measurement Duration [a], MEASURE, (AA <sub>HEX</sub> ) [ms]	Typical 3-Sigma Noise for SSC-Corrected Output <sup>[b]</sup> [counts]
16	16	2.8	5.7
16	17	3.2	10.5
16	18	3.7	18.0

- [a] Measurement duration is defined as the time from the high/low transition on the EOC pin at the beginning of the measurement until the next low/high transition on the EOC signal at the end of a single measurement in Sleep Mode.
- [b] Reference noise values normalized to the external sensor's ADC resolution; obtained with the setup: 20kΩ sensor bridge, 25°C operating temperature, gain=52, ADC offset=25%, VDD=1.8V.

### 2.3.3 Selection of Gain and Offset - Sensor System Dimensioning

The optimal gain (and offset) setup for a specific sensor element can be determined by the following steps:

- 1. Collect sensor element's characteristic, statistical data (over temperature, ambient sensor parameter, and over production tolerances):
  - a. Minimum differential output voltage:  $V_{min}$
  - b. Maximum differential output voltage:  $V_{max}$

*Note:* The best possible setup can only be determined if the absolute value of  $V_{max}$  is greater than the absolute value of  $V_{min}$ . If this is not the case, the gain polarity should be reversed by means of the *Gain\_polarity* bit in the *SM\_config* register (see section 3.6.2).

- 2. Calculate:
  - a. Common mode level; i.e., differential offset of the sensor output:

$$V_{CM} = 0.5 * (V_{max} + V_{min})$$

b. Relative or percent offset of the sensor output:

Offset<sub>sensor</sub>[%] = 
$$\frac{V_{CM}}{V_{max} - V_{min}} * 100\%$$

- 3. Determine which of the two following cases is valid.
  - a. If Offset<sub>sensor</sub> [%] > 43% then select Offset = 111 (i.e., 43.25%)
  - b. If  $0\% < Offset_{sensor}[\%] < 43\%$  then select  $Offset \le Offset_{sensor}[\%]$  (see Table 2.5 for possible ADC Offset setup values)
- 4. The total required, optimum gain can be determined as

$$Gain_{total, opt} = \frac{1.4V}{V_{max} * \left(1 - \frac{Offset_{sensor}}{100}\right)}$$

Configure gain factors in the following step such that  $Gain_{total,opt} \le Gain_{total,opt}$  (see section 2.3.1).

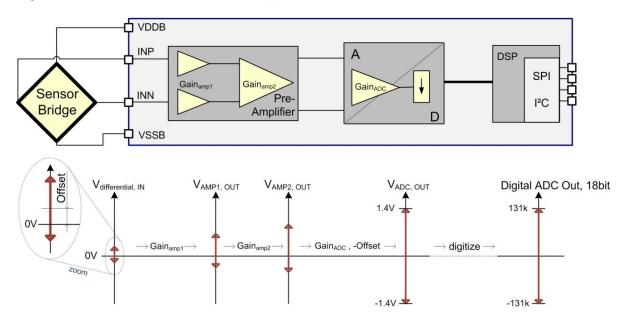
5. The gain setup can be separated into the three factors *Gain*<sub>amp1</sub>, *Gain*<sub>amp2</sub> (for the stage 2 amplifier) and *Gain*<sub>ADC</sub> (1 for no-shift or 2 for shift operation) according to

$$Gain_{total} = Gain_{amp1} * Gain_{amp2} * Gain_{ADC}$$

- a. If no offset shift is performed (Shift method = 0 and Offset = 000), the amplifier gain is Gaintotal
- b. If an offset shift is performed (Shift\_method = 1), the amplifier gain is 0.5 \* Gaintotal.



Figure 2.3 ADC Gain and Offset Setup



### 2.3.4 Temperature Measurement

The ZSSC3018 provides an internal temperature sensor measurement to allow compensation for temperature effects. See section 1.3 for the temperature sensor resolution. The temperature output signal is a differential voltage that is adapted by the amplifier for the ADC input.

For temperature measurements, the respective settings are defined and programmed to the MTP by Renesas.

### 2.3.5 External Sensor Supply: Bridge Sensors

The ZSSC3018 provides dedicated supply pins VDDB and VSSB for resistive bridge-type sensors ( $AbsV\_enable$  bit[11]=0 in  $SM\_config$  registers  $12_{HEX}$  or  $16_{HEX}$ ; see section 3.6.2). The ADC reference voltages for the sensor bridge measurement are derived from these internal voltages such that bridge supply disturbances are suppressed. The current drive ability of  $V_{DDB}$  is limited (see  $I_{VDDB}$  in section 1.2).

## 2.3.6 External Sensor: Absolute Voltage Source Sensors

As an optional alternative to a bridge sensor application, the ZSSC3018 can process signals from an absolute-voltage source sensor; e.g., a thermopile element. The respective input type can be selected with  $AbsV\_enable$  bit [11]=1 in  $SM\_config$ , registers  $12_{HEX}$  or  $16_{HEX}$ . The absolute-voltage source sensor element must be connected between the INP and INN pins; INN is internally connected to the ZSSC3018's analog ground (important: this is not VSSB). Do not connect VDDB and VSSB if an absolute-voltage source sensor is applied. The offset shift should be set to maximum in this case:  $Shift\_method = 1$  and Offset = 111 in  $SM\_config$ . The required gain can be determined according to the procedure described in section 2.3.3.



## 2.4 Digital Section

### 2.4.1 Digital Signal Processor (DSP) Core

The DSP core block performs the algorithm for correcting the sensor signal. The required coefficients are stored in the MTP memory.

When the measurement results are available, the "end of conversion" signal is set at the EOC pin if no interrupt-threshold has been set up (bits [8:7]=00 in register 02<sub>HEX</sub>; see section 3.6.2). The internal EOC information is valid only if both the measurement <u>and</u> calculation have been completed. Alternatively, the EOC pin can indicate exceeding or underrunning a specified threshold or leaving a valid-result range as described in section 3.3.

### 2.4.2 MTP Memory

The ZSSC3018's memory is designed with a true multiple-time programmable (MTP) structure. The memory is organized in 16-bit registers that can be re-written multiple (at least 1000) times. The user has access to a 57 x 16-bit storage area for values such as calibration coefficients. The required programming voltage is generated internally in the ZSSC3018. A checksum of the whole memory is evaluated for integrity-checking purposes. The checksum can be generated with command 90<sub>HEX</sub> (see section 3.4.1).

#### 2.4.3 Clock Generator

The clock generator provides approximately 4MHz, and 1MHz clock signals as the time base for IC-internal signal processing. The frequency is trimmed during production test.

### 2.4.4 Power Supervision

The power supervision block, which is a part of the voltage regulator combined with the digital section, monitors all power supplies to ensure a defined reset of all digital blocks during power-up or power supply interruptions. "Brown-out" events at the supply that do not meet the power-on-reset (POR) requirements (see Table 1.3), must be resolved with a reset pulse at the RES pin.

#### 2.4.5 Interface

The ZSSC3018 can communicate with the user's communication master or computer via an SPI or I<sup>2</sup>C interface \*. The interface type is selectable by the first activity at the interface immediately after power-up or reset:

- If the first command is an I2C command and the SS pin has been inactive until this command is received, the ZSSC3018 enters I2C Mode.
- b. If the first interface action sets the SS pin to active (active-HIGH or active-LOW dependents on the SS\_polarity bit[9] in register 02<sub>HEX</sub>; see section 3.6.2), then the ZSSC3018 enters SPI Mode.

Note: During the initiation sequence (after power-up or reset) any potential transition on SS is ignored. Switching to SPI Mode is only possible after the power-up sequence. If SS is not connected, the SS pin internal pull-up keeps the ZSSC3018 in I<sup>2</sup>C<sup>TM</sup> Mode.

To also provide interface accessibility in Sleep Mode (all features inactive except the digital interface logic), the interface circuitry is directly supplied by VDD.

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<sup>\*</sup> Functional I<sup>2</sup>C interface properties correspond to the NXP I<sup>2</sup>C Bus Specification Rev. 0.3 (June 2009).



# 3. Functional Description

## 3.1 Power-Up

Specifications related to power-up are given in sections 1.2 and 1.3. On power-up, the ZSSC3018 communication interface is able to receive the first command after the time  $t_{STA1}$  from when the VDD supply is within operating specifications. The ZSSC3018 can begin the first measurement after the time  $t_{STA2}$  from when the VDD supply is operational. As an alternative to a power-on-reset, a reset and new power-up-sequence can be triggered by an IC-reset signal (high low) at the RES pin.

The wake-up time from Sleep Mode to Active State (see section 3.3) after receiving the activating command is defined as twop1 and twop2. In Command Mode, subsequent commands can be sent after twop1. The first measurement starts after twop2 if a measurement request has been sent.

### 3.2 Measurements

Available measurement procedures are

- AZSM: auto-zero (external) sensor measurement
- SM: (external) sensor measurement
- AZTM: auto-zero temperature measurement
- TM: temperature measurement

**AZSM:** The configuration for the external sensor measurement, i.e. a resistive bridge or an absolute-voltage source, is loaded. The multiplexer block connects the amplifier input to the AGND analog ground reference. An analog-to-digital conversion is performed so that the inherent system offset for the respective configuration is converted by the ADC to a digital value, quantized according to the respective MTP configuration.

**SM:** The configuration for the external sensor measurement, i.e. a resistive bridge or an absolute-voltage source, is loaded. The multiplexer connects the amplifier input to the INP and INN pins accordingly. An analog-to-digital conversion is performed. The result is a digital value with a resolution according to the MTP configuration.

**AZTM:** The configuration for temperature measurements is loaded. The multiplexer connects the amplifier input to AGND. An analog-to-digital conversion is performed so that the inherent system offset for the temperature configuration is converted by the ADC to a digital value, quantized according to the respective MTP configuration.

**TM:** The configuration for temperature measurements is loaded. The multiplexer connects the amplifier input to the internal temperature sensor. An analog-to-digital conversion is performed. The result is a digital value with a resolution according to the MTP configuration.

The typical application's measurement cycle is a complete SSC measurement (using one of the commands AA<sub>HEX</sub> to AF<sub>HEX</sub>) with AZSM, SM, AZTM, and TM followed by a signal correction calculation.

# 3.3 Interrupt (EOC Pin)

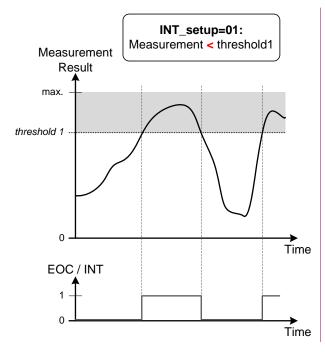
The EOC pin can be programmed to operate either as a pure "measurement busy" and end-of-conversion (EOC) transducer, or as a configurable interrupt transducer. The respective basic operation must be programmed to the  $INT\_setup$  bits [1:0] in register  $02_{HEX}$ [8:7] (see section 3.6.2). One or two 24-bit-quantized thresholds can be programmed (TRSH1, TRSH2 in memory registers  $13_{HEX}$ ,  $14_{HEX}$  and  $15_{HEX}$ ).

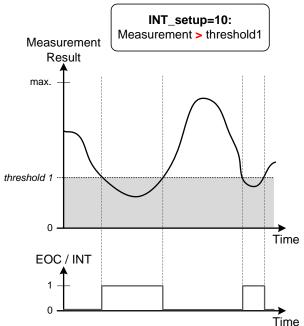
Dependent on the *INT\_setup* selection, the EOC pin provides a logic 1 or logic 0 (also dependent on the respective interface setup; e.g., SPI with logic 0  $\Leftrightarrow$  VDD or logic 0  $\Leftrightarrow$  VSS, etc.) according to the SSC-corrected result. The respective thresholds are programmed left-aligned in the memory, such that they must be programmed with the threshold's MSB in the memory register's MSB, etc. The LSBs of the 24-bit threshold in the memory must be truncated to the number of bits of the selected ADC resolution (according to *Adc\_bits*).



The interrupt functionality is only available for digital values from the SSC-calculation unit – raw values cannot be monitored by the interrupt feature. Figure 3.1 and Figure 3.2 show the different setup options and the respective response at the EOC pin. The use of the interrupt functionality is recommended for cyclic operation. Only in cyclic operation (command AB<sub>HEX</sub> with respective power-down setup in the 02<sub>HEX</sub> register *Interface Configuration*), the EOC-level continuously represents the respective SSC-measurement result. For single or oversample measurement requests without cyclic operation, the EOC output signal is reset to logical zero at the beginning of each new measurement, even though the interrupt thresholds are established correctly (setting EOC to logical one or zero is dependent on interrupt setup) at the end of each measurement.

Figure 3.1 Interrupt Functionality: INT\_setup = 01 and INT\_setup = 10





Time



INT\_setup=11 Case A: Case B: Measurement Measurement threshold1 > threshold2 threshold1 < threshold2 Result Result max. max. threshold 1 threshold 2 threshold 2 threshold 1 <del>→</del> Time Ťime

Time

Figure 3.2 Interrupt Functionality: INT\_setup = 11

## 3.4 Operational Modes

**EOC / INT** 

Figure 3.3 illustrates the ZSSC3018 power-up sequence and subsequent operation depending on the selected interface communication mode (I<sup>2</sup>C or SPI) as determined by interface related first activities after power-up or reset. If the first command after power-up is a valid I<sup>2</sup>C<sup>TM</sup> command, the interface will react as an I<sup>2</sup>C interface until the next power-on-reset (POR). If there is no valid I<sup>2</sup>C command, but an active signal at the SS pin is detected as the first valid activity, then the interface will respond as an SPI slave. With either interface, after the voltage regulators are switched on, the ZSSC3018's low voltage section (LV) is active while the related interface configuration information is read from memory. Then the LV section is switched off, the ZSSC3018 goes into Sleep Mode, and the interface is ready to receive commands. Since the interface is always powered by V<sub>DD</sub>, it is referred to as the high voltage section (HV).

EOC / INT

See Table 3.1 for definitions of the commands.

Figure 3.4 shows the ZSSC3018 operation in Normal Mode (with two operation principles: "Sleep" and "Cyclic") and Command Mode including when the LV and HV sections are active as indicated by the color legend. The Normal Mode automatically returns to Sleep Mode after executing the requested measurements, or periodically wakes up and conducts another measurement according to the selection of the "sleep duration" with the *CYC\_period* (bits[14:12] in memory register 02<sub>HEX</sub>). In Command Mode, the ZSSC3018 remains active if a dedicated command (Start\_NOM) has been sent, which is helpful during calibration. Command Mode can only be entered if Start\_CM (command A9<sub>HEX</sub>; see Table 3.1) is the first command received after POR.



Figure 3.3 Operational Flow Chart: Power Up

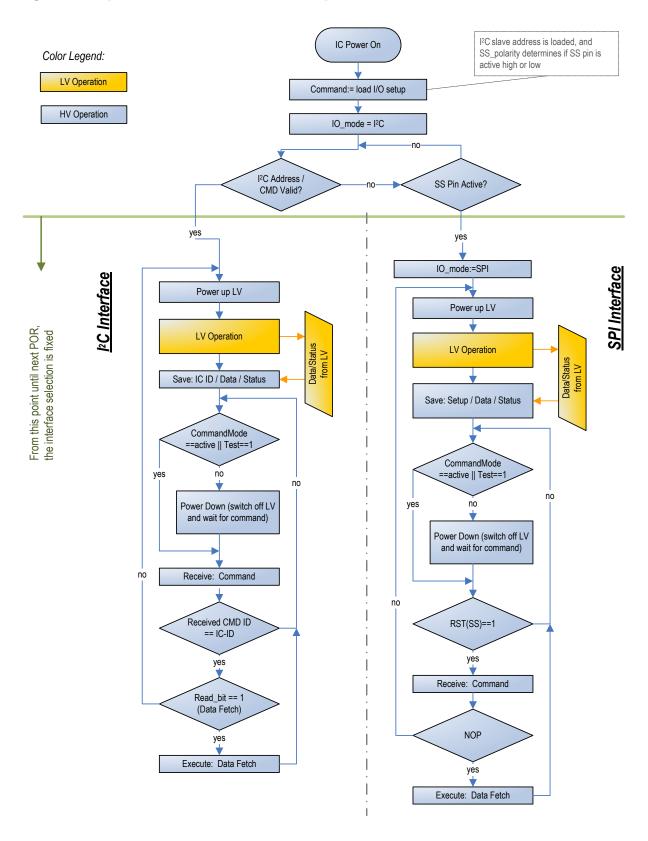
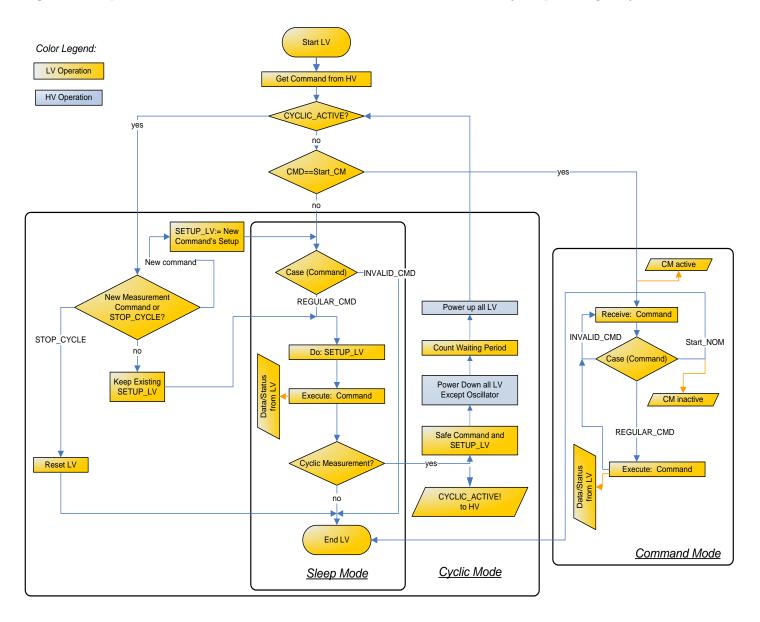




Figure 3.4 Operational Flow Chart: Command Mode and Normal Mode (Sleep and Cyclic)





### 3.4.1 SPI/I<sup>2</sup>C Commands

The SPI/I<sup>2</sup>C commands supported by the ZSSC3018 are listed in Table 3.1. The command to read an address in the user memory is the same as its address. The command to write to an address in user memory is the address plus 40<sub>HEX</sub>.

There is a Renesas-reserved section of memory that can be read but not over-written by the user.

### Table 3.1 SPI/I<sup>2</sup>C Commands

Note: Every return starts with a status byte followed by the data word as described in section 3.5.1.

Note: The output for any ADC measurement and signal conditioning calculation is formatted as a 24-bit data word, regardless of the effective ADC resolution used.

Command (Byte)	Return	Description	Normal Mode	Command Mode
00 <sub>HEX</sub> to 39 <sub>HEX</sub>	16-bit user data	Read data in the user memory address ( $00_{\text{HEX}}$ to $39_{\text{HEX}}$ ) matching the command (might not be using all addresses).	yes	yes
3A <sub>HEX</sub> to 3F <sub>HEX</sub>	16-bit Renesas-reserved memory data	Read data in Renesas-reserved memory at address (3A <sub>HEX</sub> to 3F <sub>HEX</sub> ).	yes	yes
40 <sub>HEX</sub> to 79 <sub>HEX</sub> followed by data (0000 <sub>HEX</sub> to FFFF <sub>HEX</sub> )	_	Write data to user memory at address specified by command minus 40 <sub>HEX</sub> (addresses 00 <sub>HEX</sub> to 39 <sub>HEX</sub> respectively; might not be using all addresses).	yes	yes
90 <sub>HEX</sub>	_	Calculate and write memory checksum (CRC)	yes	yes
A0 <sub>HEX</sub> to A7 <sub>HEX</sub> followed by XXXX <sub>HEX</sub> (see Table 3.2)	24-bit formatted raw data	Get_Raw This command can be used to perform a measurement and write the raw ADC data into the output register. The LSB of the command determines how the AFE configuration register is loaded for the Get_Raw measurement (see Table 3.2).	yes	yes
A8 <sub>HEX</sub>	-	Start_NOM Exit Command Mode and transition to Normal (Sleep or Cyclic) Mode.	no	yes
A9 <sub>HEX</sub>	-	<b>Start_CM</b> Exit Normal Mode and transition to Command Mode (as very first command after power-up).	yes	no
AA <sub>HEX</sub>	24-bit formatted fully corrected sensor measurement data + 24-bit corrected temperature data	<b>Measure</b> Triggers full measurement cycle (AZSM, SM, AZTM, and TM, as described in section 3.2) and calculation and storage of data in interface (configurations from MTP).	yes	yes
AB <sub>HEX</sub>	24-bit formatted fully corrected sensor measurement data + 24-bit corrected temperature data	Measure Cyclic Triggers continuous full measurement cycle (AZSM, SM, AZTM, and TM, as described in section 3.2) and calculation and storage of data in interface (configurations from MTP) followed by pause according to CYC_period (bits[14:12] in register 02 <sub>HEX</sub> )	yes	yes



Command (Byte)	Return	Description	Normal Mode	Command Mode
AC <sub>HEX</sub>	24-bit formatted fully corrected sensor measurement data + 24-bit corrected temperature data	Oversample-2 Measure Mean value generation: 2 full measurements (as in command AA <sub>HEX</sub> ) are conducted, the mean value of the measurements is calculated, and the data is stored in the interface (configurations from MTP); no power down or pause between the 2 measurements	yes	yes
ADHEX	24-bit formatted fully corrected sensor measurement data + 24-bit corrected temperature data	Oversample-4 Measure Mean value generation: 4 full measurements (as in command AA <sub>HEX</sub> ) are conducted, the mean value of the measurements is calculated, and the data is stored in the interface (configurations from MTP), no power down or pause between the 4 measurements	yes	yes
AE <sub>HEX</sub>	24-bit formatted fully corrected sensor measurement data + 24-bit corrected temperature data	Oversample-8 Measure Mean value generation: 8 full measurements (as in command AA <sub>HEX</sub> ) are conducted, the mean value of the measurements is calculated, and the data is stored in the interface (configurations from MTP), no power down or pause between the 8 measurements	yes	yes
AF <sub>HEX</sub>	24-bit formatted fully corrected sensor measurement data + 24-bit corrected temperature data	Oversample-16 Measure Mean value generation: 16 full measurements (as in command AA <sub>HEX</sub> ) are conducted, the mean value of the measurements is calculated, and the data is stored in the interface (configurations from MTP), no power down or pause between the 16 measurements	yes	yes
B0 <sub>HEX</sub>	-	Select 1 <sup>st</sup> , SM_config1 register (12 <sub>HEX</sub> in memory) For any measurement using the memory content for analog front-end / sensor setup, the respective setup is loaded from SM_config1 register, status bit[1]==0 (default)	yes	yes
B1 <sub>HEX</sub>	_	Select 2 <sup>nd</sup> , SM_config2 register (16 <sub>HEX</sub> in memory) For any measurement using the memory content for analog front-end / sensor setup, the respective setup is loaded from the SM_config2 register, status bit[1]==1	yes	yes
BF <sub>HEX</sub>	-	STOP_CYC Causes power-down leading to halting update / cyclic measurement operation and transition from Normal to Sleep Mode.	yes	yes
FX <sub>HEX</sub>	Status followed by last 24-bit data	<b>NOP</b> Only valid for SPI (see sections 3.5.1 and 3.5.2).	yes	yes



## Table 3.2 Get\_Raw Commands

Command	Measurement	AFE Configuration Register
A0 <sub>HEX</sub> followed by 0000 <sub>HEX</sub>	SM – Sensor Measurement	SM_config
A1 <sub>HEX</sub> followed by ssss <sub>HEX</sub>	SM – Sensor Measurement	ssss is the user's configuration setting for the measurement provided via the interface. The format and purpose of the configuration bits must be according to the definitions for <i>SM_config</i> .
A2 <sub>HEX</sub> followed by 0000 <sub>HEX</sub>	SM-AZSM – Auto-Zero Corrected Sensor Measurement [a]	SM_config
A3 <sub>HEX</sub> followed by ssss <sub>HEX</sub>	SM-AZSM – Auto-Zero Corrected Sensor Measurement [b]	ssss is the user's configuration setting for the measurement provided via the interface. The format and purpose of configuration bits must be according to the definitions for <i>SM_config</i> .
A4 <sub>HEX</sub> followed by 0000 <sub>HEX</sub>	TM – Temperature Measurement	Renesas-defined register
A5 <sub>HEX</sub> followed by ssss <sub>HEX</sub>	TM – Temperature Measurement	ssss is the user's configuration setting for the measurement provided via the interface. The format and purpose of configuration bits must be according to the definitions for <i>SM_config</i> and valid for temperature measurement in this case (bits [15:13] will be ignored).
A6 <sub>HEX</sub> followed by 0000 <sub>HEX</sub>	TM-AZTM – Auto-Zero Corrected Temperature Measurement [a]	Renesas-defined register
A7 <sub>HEX</sub> followed by ssss <sub>HEX</sub>	TM-AZTM – Auto-Zero Corrected Temperature Measurement [b]	ssss is the user's configuration setting for the measurement provided via the interface. The format and purpose of configuration bits must be according to the definitions for <i>SM_config</i> being valid for temperature measurement in this case (bits [15:13] will be ignored).

<sup>[</sup>a] Recommended for raw data collection during calibration coefficient determination using pre-programmed (in MTP) measurement setups.

<sup>[</sup>b] Recommended for raw data collection during calibration coefficient determination using un-programmed (not in MTP), external measurement setups; e.g., for evaluation purposes.



### 3.5 Communication Interface

### 3.5.1 Common Functionality

Commands are handled by the command interpreter in the LV section. Commands that need additional data are not treated differently than other commands because the HV interface is able to buffer the command and all the data that belongs to the command and the command interpreter is activated as soon as a command byte is received.

Every response starts with a status byte followed by the data word. The data word depends on the previous command. It is possible to read the same data more than once if the read request is repeated (I<sup>2</sup>C) or a NOP command is sent (SPI). If the next command is not a read request (I<sup>2</sup>C) or a NOP (SPI), it invalidates any previous data.

The ZSSC3018 supports the parallel setup of two amplifier-ADC configurations by means of *SM\_config1* (default) and *SM\_config2*. Switching between the two setups can be done with the commands B0<sub>HEX</sub> (selects *SM\_config1*) and B1<sub>HEX</sub> (selects *SM\_config2*), whereas the respective activation command must always be sent prior to the measurement request.

The status byte contains the following bits (see Table 3.3, for sequence):

- Power indication (bit 6): 1 if the device is powered (V<sub>DDB</sub> on); 0 if not powered. This is needed for SPI Mode where the master reads all zeros if the device is not powered or in power-on reset (POR).
- Busy indication (bit 5): 1 if the device is busy, which indicates that the data for the last command is not available yet. No new commands
  are processed if the device is busy.
  - *Note:* The device is always busy if the cyclic measurement operation has been set up and started.
- Actual ZSSC3018 mode (bits 4:3): 00 = Normal Mode; 01 = Command Mode; 1X = Renesas-reserved. See Table 3.4.
- Memory integrity/error flag (bit 2): 0 if integrity test passed, 1 if test failed. This bit indicates whether the checksum-based integrity check passed or failed. The memory error status bit is calculated only during the power-up sequence, so a newly written CRC will only be used for memory verification and status update after a subsequent ZSSC3018 power-on reset (POR) or reset by means of the RES pin.
- Config Setup (bit 1): Indicates the selection of the SM\_config register being used (register 12<sub>HEX</sub>: SM\_config1 or register 16<sub>HEX</sub>: SM\_config2). The respective separate configuration setup allows two different configurations of the external sensor channel in order to support up to two application scenarios with the use of only one sensor-IC pair. This bit is 0 (default) if SM\_config1 was selected. This bit is 1 if SM\_config2 was selected.
- ALU saturation (bit 0): If the last command was a measurement request, this bit is 0 if any intermediate value and the final SSC result are
  in a valid range and no SSC-calculation internal saturation occurred, respectively. If the last command was a measurement request, this
  bit is 1 if an SSC-calculation internal saturation occurred. This bit is also 0 for any non-measurement command.

#### **Table 3.3 General Status Byte**

Bit	7	6	5	4	3	2	1	0
Meaning	0	Powered?	Busy?	Мо	de	Memory error?	Config Setup	ALU Saturation

#### Table 3.4 Mode Status

Status[4:3]	Mode
00	Normal Mode (sleep and cyclic operations)
01	Command Mode
10	Renesas-Reserved
11	Command Mode and Reserved



Further status information can be provided by the EOC pin. The EOC pin is set high when a measurement and calculation have been completed (if no interrupt threshold is used; i.e., *INT\_setup*==00<sub>BIN</sub>, see section 3.3).

#### 3.5.2 SPI

The SPI Mode is available if the very first interface activity (after ZSSC3018 power-up) is an active signal at the SS pin. The polarity and phase of the SPI clock are programmable via the *CKP\_CKE* setting in register 02<sub>HEX</sub> as described in Table 3.5. *CKP\_CKE* is two bits: CPHA (bit 10), which selects which edge of SCLK latches data, and CPOL (bit 11), which indicates whether SCLK is high or low when it is idle. The polarity of the SS signal and pin are programmable via the *SS\_polarity* setting (bit 9). The different combinations of polarity and phase are illustrated in the figures below.

Figure 3.5 SPI Configuration CPHA=0

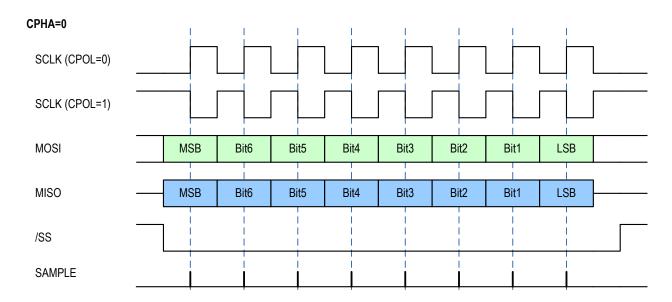
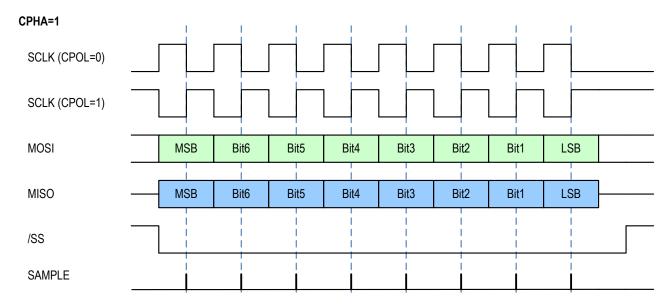


Figure 3.6 SPI Configuration CPHA=1





In SPI Mode, each command except NOP is started as shown in Figure 3.7. After the execution of a command (busy = 0), the expected data can be read as illustrated in Figure 3.8 or if no data are returned by the command, the next command can be sent. The status can be read at any time with the NOP command (see Figure 3.9).

### Figure 3.7 SPI Command Request

### **Command Request**



Note: A command request always consists of 3 bytes. If the command is shorter, then it must be completed with 0s.

The data on MISO depend on the preceding command.

## Figure 3.8 SPI Read Status

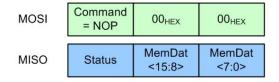
### **Read Status**



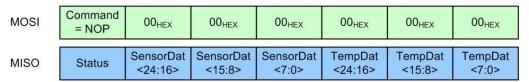
## Figure 3.9 SPI Read Data

### **Read Data**

(a) Example: after the completion of a Memory Read command



(b) Example: after the completion of a Full Measurement command (AA<sub>HEX</sub>)





### 3.5.3 I<sup>2</sup>C

I<sup>2</sup>C Mode will be selected if the very first interface activity (after IC power-up) is an I<sup>2</sup>C command. In I<sup>2</sup>C Mode, each command is started as shown in Figure 3.10. Only the number of bytes that is needed for the command must be sent. An exception is the I<sup>2</sup>C High Speed Mode (controlled by the *Slave\_Addr* bit field in register 02<sub>HEX</sub> in Table 3.5) where 3 bytes must always be sent as in SPI Mode. After the execution of a command (busy = 0), the expected data can be read as illustrated in Figure 3.12 or if no data are returned by the command, the next command can be sent. The status can be read at any time as illustrated in Figure 3.11.

Figure 3.10 I<sup>2</sup>C Command Request

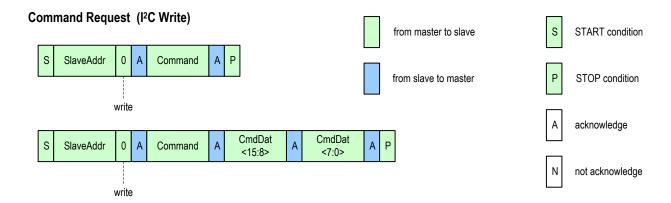


Figure 3.11 I<sup>2</sup>C Read Status

# Read Status (I<sup>2</sup>C Read)

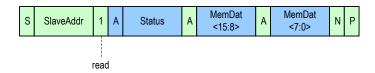




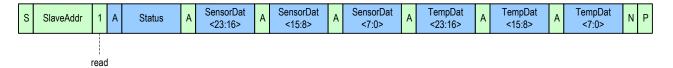
### Figure 3.12 I<sup>2</sup>C Read Data

#### Read Data (I<sup>2</sup>C Read)

(a) Example: after the completion of a Memory Read command



(b) Example: after the completion of a Measure command (AA<sub>HEX</sub>)



All mandatory I<sup>2</sup>C-bus protocol features are implemented. Optional features like clock stretching, 10-bit slave address, etc., are not supported by the ZSSC3018's interface.

In I<sup>2</sup>C High Speed Mode, a command consists of a fixed length of three bytes.

## 3.6 Memory

In the ZSSC3018, the memory is organized in 16-bit wide registers and can be programmed multiple (at least 1000) times (MTP). There are 57 x 16-bit registers available for customer use. Each register can be re-programmed. Basically, there are two MTP content sectors:

- Customer Use: Accessible by means of regular write operations (40<sub>HEX</sub> to 79<sub>HEX</sub>). It contains: the customer ID, interface setup data, measurement setup information, calibration coefficients, etc.
- Renesas Use: Only accessible for write operations by Renesas. The Renesas sector contains specific trim information and is programmed during manufacturing test by Renesas.

## 3.6.1 Programming Memory

Programming memory is possible with any specified supply voltage level at VDD. The MTP programming voltage itself is generated by means of an integrated charge pump, generating an internal memory programming voltage; no additional external voltage, other than VDD (as specified), needed. A single 16-bit register write will be completed within 16ms after the respective programming command has been sent. After the memory is programmed, it must be read again to verify the validity of the memory contents.



## **3.6.2 Memory Contents**

**Table 3.5 MTP Memory Content Assignments** 

MTP Address	Word / Bit Range	Default Setting	Description	Notes / Explanations
00 <sub>HEX</sub>	15:0	0000 <sub>HEX</sub>	Cust_ID0	Customer ID byte 0 (combines with memory word 01 <sub>HEX</sub> to form customer ID)
01 <sub>HEX</sub>	15:0	0000 <sub>HEX</sub>	Cust_ID1	Customer ID byte 1 (combines with memory word $00_{\text{HEX}}$ to form customer ID)
Interface Config	guration			
	6:0	000 0000 <sub>BIN</sub>	Slave_Addr	I <sup>2</sup> C slave address; valid range: 00 <sub>HEX</sub> to 7F <sub>HEX</sub> (default: 00 <sub>HEX</sub> ). Note: address codes 04 <sub>HEX</sub> to 07 <sub>HEX</sub> are reserved for entering the I <sup>2</sup> C High Speed Mode
				Interrupt configuration, EOC pin functionality:  00 End-of-conversion signal  01 0-1 transition if threshold1 (TRSH1) is exceeded
				and 1-0 transition if threshold1 is underrun again  10 0-1 transition if threshold1 is underrun and 1-0 transition if threshold1 is exceeded again
	8:7	00 <sub>BIN</sub>	INT_setup	11 EOC is determined by threshold settings (see section 3.3):
				If (TRSH1 > TRSH2) then EOC/INT (interrupt level) = 0 if (TRSH1 > MEAS ≥ TRSH2) where MEAS is the conditioned measurement result. Otherwise EOC/INT=1.
02 <sub>HEX</sub>				If (TRSH1 ≤ TRSH2) then EOC/INT = 1 if (TRSH1 ≤ MEAS < TRSH2). Otherwise EOC/INT = 0.
				Determines the polarity of the Slave Select pin (SS) for SPI operation:
	9	OBIN	SS_polarity	0 ⇔ Slave Select is active LOW (SPI and ZSSC3018 are active if SS==0)
				1 ⇔ Slave Select is active HIGH (SPI and ZSSC3018 are active if SS==1)
				Clock polarity and clock-edge select—determines polarity and phase of SPI interface clock with the following modes:
	11:10	00 <sub>BIN</sub>		00 ⇔ SCLK is low in idle state, data latch with rising edge and data output with falling edge
			CKP_CKE	01 ⇔ SCLK is low in idle state, data latch with falling edge and data output with rising edge
				10 ⇔ SCLK is high in idle state, data latch with falling edge and data output with rising edge
				11 ⇔ SCLK is high in idle state, data latch with rising edge and data output with falling edge



MTP Address	Word / Bit Range	Default Setting	Description	Notes / Explanations		
	14:12	000 <sub>BIN</sub>	CYC_period	Update period (ZSSC3018 sleep time, except oscillator) in cyclic operation:  000 ⇔ not assigned  001 ⇔ 125ms  010 ⇔ 250ms  011 ⇔ 500ms  100 ⇔ 1000ms  101 ⇔ 2000ms  111 ⇔ not assigned		
	15	O <sub>BIN</sub>	SOT_curve	Type / shape of second-order curve correction for the sensor signal.  0 ⇔ parabolic curve  1 ⇔ s-shaped curve		
Signal Conditioning Parameters						
03нех	15:0	0000 <sub>HEX</sub>	Offset_S[15:0]	Bits [15:0] of the 24-bit sensor offset correction coefficient Offset_S. (The MSBs of this coefficient including sign are Offset_S[23:16], which is bits [15:8] in 0D <sub>HEX</sub> .)		
04нех	15:0	0000 <sub>HEX</sub>	Gain_S[15:0]	Bits [15:0] of the 24-bit value of the sensor gain coefficient Gain_S. (The MSBs of this coefficient including sign are Gain_S[23:16], which is bits [7:0] in 0D <sub>HEX</sub> .)		
05 <sub>HEX</sub>	15:0	0000 <sub>HEX</sub>	Tcg[15:0]	Bits [15:0] of the 24-bit coefficient Tcg for the temperature correction of the sensor gain. (The MSBs of this coefficient including sign are Tcg[23:16], which is bits [15:8] in 0E <sub>HEX</sub> .)		
06нех	15:0	0000 <sub>HEX</sub>	Tco[15:0]	Bits [15:0] of the 24-bit coefficient Tco for temperature correction of the sensor offset. (The MSBs of this coefficient including sign are Tco[23:16], which is bits [7:0] in 0E <sub>HEX</sub> .)		
07 <sub>HEX</sub>	15:0	0000 <sub>HEX</sub>	SOT_tco[15:0]	Bits [15:0] of the 24-bit 2 <sup>nd</sup> order term SOT_tco applied to Tco. (The MSBs of this term including sign are SOT_tco[23:16], which is bits[15:8] in 0F <sub>HEX</sub> .)		
08нех	15:0	0000 <sub>HEX</sub>	SOT_tcg[15:0]	Bits [15:0] of the 24-bit 2 <sup>nd</sup> order term SOT_tcg applied to Tcg. (The MSBs of this term including sign are SOT_tcg[23:16], which is bits[7:0] in 0F <sub>HEX</sub> .)		
09 <sub>HEX</sub>	15:0	0000 <sub>HEX</sub>	SOT_sens[15:0]	Bits [15:0] of the 24-bit 2 <sup>nd</sup> order term SOT_sens applied to the sensor readout. (The MSBs of this term including sign are SOT_sens[23:16], which is bits[15:8] in 10 <sub>HEX</sub> .)		
0A <sub>HEX</sub>	15:0	0000 <sub>HEX</sub>	Offset_T[15:0]	Bits [15:0] of the 24-bit temperature offset correction coefficient Offset_T. (The MSBs of this coefficient including sign are Offset_T[23:16], which is bits[7:0] in 10 <sub>HEX</sub> .)		



MTP Address	Word / Bit Range	Default Setting	Description	Notes / Explanations
ОВнех	15:0	0000 <sub>HEX</sub>	Gain_T[15:0]	Bits [15:0] of the 24-bit absolute value of the temperature gain coefficient Gain_T. (The MSBs of this coefficient including sign are Gain_T[23:16], which is bits[15:8] in 11 <sub>HEX</sub> .)
ОСнех	15:0	0000 <sub>HEX</sub>	SOT_T[15:0]	Bits [15:0] of the 24-bit 2 <sup>nd</sup> -order term SOT_T applied to the temperature reading. (The MSBs of this coefficient including sign are SOT_T[23:16], which is bit[7:0] in 11 <sub>HEX</sub> .)
0D <sub>HEX</sub>	7:0	00 <sub>HEX</sub>	Gain_S[23:16]	Bits [23:16] including sign for the 24-bit sensor gain correction coefficient Gain_S. (The LSBs of this coefficient are Gain_S[15:0] in register 04 <sub>HEX</sub> .)
ODHEX	15:8	00 <sub>HEX</sub>	Offset_S[23:16]	Bits [23:16] including sign for the 24-bit sensor offset correction coefficient Offset_S. (The LSBs are Offset_S[15:0] in register 03 <sub>HEX</sub> .)
ОЕнех	7:0	00 <sub>HEX</sub>	Tco[23:16]	Bits [23:16] including sign for the 24-bit coefficient Tco for temperature correction for the sensor offset. (The LSBs are Tco[15:0] in register $06_{\text{HEX}}$ .)
ULHEX	15:8	00 <sub>HEX</sub>	Tcg[23:16]	Bits [23:16] including sign for the 24-bit-wide coefficient Tcg for the temperature correction of the sensor gain. (The LSBs are Tcg[15:0] in register 05 <sub>HEX</sub> .)
0F <sub>HEX</sub>	7:0	00 <sub>HEX</sub>	SOT_tcg[23:16]	Bits [23:16] including sign for the 24-bit 2 <sup>nd</sup> order term SOT_tcg applied to Tcg. (The LSBs are SOT_tcg[15:0] in register 08 <sub>HEX</sub> .)
OFHEX	15:8	00 <sub>HEX</sub>	SOT_tco[23:16]	Bits [23:16] including sign for the 24-bit 2 <sup>nd</sup> order term SOT_tco applied to Tco. (The LSBs are SOT_tco[15:0] in register 07 <sub>HEX</sub> .)
10	7:0	00 <sub>HEX</sub>	Offset_T[23:16]	Bits [23:16] including sign for the 24-bit temperature offset correction coefficient Offset_T. (The LSBs are Offset_T[15:0] in register 0A <sub>HEX</sub> .)
10 <sub>HEX</sub>	15:8	00 <sub>HEX</sub>	SOT_sens[23:16]	Bits [23:16] including sign for the 24-bit 2 <sup>nd</sup> order term SOT_sens applied to the sensor readout. (The LSBs are SOT_sens[15:0] in register 09 <sub>HEX</sub> .)
44	7:0	00 <sub>HEX</sub>	SOT_T[23:16]	Bits [23:16] including sign for the 24-bit 2 <sup>nd</sup> -order term SOT_T applied to the temperature reading. (The LSBs are SOT_T[15:0] in register 0C <sub>HEX</sub> .)
11 <sub>HEX</sub>	15:8	00 <sub>HEX</sub>	Gain_T[23:16]	Bits [23:16] including sign for the 24-bit absolute value of the temperature gain coefficient Gain_T. (The LSBs are Gain_T[15:0] in register 0B <sub>HEX</sub> .)



MTP Address	Word / Bit Range	Default Setting	Description	Notes / Explanations
1 <sup>st</sup> Measuremer	nt Configuration	Register (SM_c	config1)	
	2:0	000вім	Gain_stage1	Gain setting for the 1st PREAMP stage with Gain_stage1 ⇔ Gain_amp1:  000 ⇔ 6  001 ⇔ 12  010 ⇔ 20  011 ⇔ 30  100 ⇔ 40  101 ⇔ 60  110 ⇔ 80  111 ⇔ 120 (Might affect noise and accuracy specifications depending on sensor setup)
5:3 12 <sub>HEX</sub>	5:3	000 <sub>BIN</sub>	Gain_stage2	Gain setting for the $2^{nd}$ PREAMP stage with Gain_stage2 $\Leftrightarrow$ Gain_amp2: $000 \Leftrightarrow 1.1$ $001 \Leftrightarrow 1.2$ $010 \Leftrightarrow 1.3$ $011 \Leftrightarrow 1.4$ $100 \Leftrightarrow 1.5$ $101 \Leftrightarrow 1.6$ $110 \Leftrightarrow 1.7$ $111 \Leftrightarrow 1.8$
	6	O <sub>BIN</sub>	Gain_polarity	Set up the polarity of the sensor bridge's gain (inverting of the chopper) with  0 ⇔ positive (no polarity change)  1 ⇔ negative (180° polarity change)
	10:7	0000 <sub>BIN</sub> (0100 <sub>BIN</sub> )	Adc_bits	Absolute number of bits for the ADC conversion ADC_bits:  0000 ⇔ 12-bit  0001 ⇔ 13-bit  0010 ⇔ 14-bit  0011 ⇔ 15-bit  0100 ⇔ 16-bit  0101 ⇔ 17-bit  0110 ⇔ 18-bit  0111 to 1111 ⇔ not assigned



MTP Address	Word / Bit Range	Default Setting	Description	Notes / Explanations
	11	O <sub>BIN</sub>	AbsV_enable	Enable bit for thermopile input selection (INN connected to AGND, INP connected absolute voltage source) with AbsV_enable:  0 ⇔ absolute voltage input disabled (default)  1 ⇔ absolute voltage input enabled (e.g. for a thermopile)
	14:12	000вім	Offset	Differential signal's offset shift in ADC; compensation of x% signal offset:  000 ⇔ no offset compensation  001 ⇔ 6.75% offset  010 ⇔ 12.5% offset  011 ⇔ 19.25% offset  100 ⇔ 25% offset  101 ⇔ 31.75% offset  101 ⇔ 38.5% offset  110 ⇔ 38.5% offset  110 ⇔ 38.5% offset  111 ⇔ 43.25% offset  Note: Shift_method (bit 15 below) must be set to 1 to enable the offset shift.
	15	O <sub>BIN</sub>	Shift_method	Offset shift method selection:  0 ⇔ No offset shift, Offset (bits[14:12] in 12 <sub>HEX</sub> ) must be set to 000BIN, GainADC = 1  1 ⇔ Offset shift ADC, GainADC = 2
13 <sub>HEX</sub>	15:0	0000 <sub>HEX</sub>	TRSH1[15:0]	Bits [15:0] of the 24-bit interrupt threshold1, TRSH1. (The MSB bits for this threshold are TRSH1[23:16], which is bits [7:0] of register 15 <sub>HEX</sub> .)
14 <sub>HEX</sub>	15:0	0000 <sub>HEX</sub>	TRSH2[15:0]	Bits [15:0] of the 24-bit interrupt threshold2, TRSH2. (The MSB bits for this threshold are TRSH2[23:16], which is bits[15:8] of register 15 <sub>HEX</sub> .)
15 <sub>HEX</sub>	7:0	00 <sub>HEX</sub>	TRSH1[23:16]	Bits [23:16] of the 24-bit interrupt threshold1, TRSH1. (The LSB bits for this threshold are TRSH1[15:0], which is bits[15:0] of register 13 <sub>HEX</sub> .)
	15:8	00 <sub>HEX</sub>	TRSH2[23:16]	Bits [23:16] of the 24-bit interrupt threshold2, TRSH2. (The LSB bits for this threshold are TRSH2[15:0], which is bits[15:0] of register 14 <sub>HEX</sub> .)



MTP Address	Word / Bit Range	Default Setting	Description	Notes / Explanations			
2 <sup>nd</sup> Measurement Configuration Register (SM_config2)							
16 <sub>HEX</sub>	2:0	000вім	Gain_stage1	Gain setting for the 1st PREAMP stage with Gain_stage1 ⇔ Gain_amp1:  000 ⇔ 6  001 ⇔ 12  010 ⇔ 20  011 ⇔ 30  100 ⇔ 40  101 ⇔ 60  110 ⇔ 80  111 ⇔ 120 (Might affect noise and accuracy specifications depending on sensor setup)			
	5:3	000 <sub>BIN</sub>	Gain_stage2	Gain setting for the $2^{nd}$ PREAMP stage with $6^{nd}$ Stage $2 \Leftrightarrow 6^{nd}$ Gain_ $2^{nd}$ Gain_ $2^{$			
	6	O <sub>BIN</sub>	Gain_polarity	Set up the polarity of the sensor bridge's gain (inverting of the chopper) with  0 ⇔ positive (no polarity change)  1 ⇔ negative (180° polarity change)			
	10:7	0000 <sub>BIN</sub> (0100 <sub>BIN</sub> )	Adc_bits	Absolute number of bits for the ADC conversion ADC_bits:  0000 ⇔ 12-bit  0001 ⇔ 13-bit  0010 ⇔ 14-bit  0011 ⇔ 15-bit  0100 ⇔ 16-bit  0101 ⇔ 17-bit  0110 ⇔ 18-bit  0111 to 1111 ⇔ not assigned			



MTP Address	Word / Bit Range	Default Setting	Description	Notes / Explanations
	11	O <sub>BIN</sub>	AbsV_enable	Enable bit for thermopile input selection (INN connected to AGND, INP connected absolute voltage source) with AbsV_enable:  0 ⇔ absolute voltage input disabled (default)  1 ⇔ absolute voltage input enabled (e.g. for a thermopile)
	14:12	000 <sub>BIN</sub>	Offset	Differential signal's offset shift in ADC; compensation of x% signal offset:  000 ⇔ no offset compensation  001 ⇔ 6.75% offset  010 ⇔ 12.5% offset  011 ⇔ 19.25% offset  100 ⇔ 25% offset  101 ⇔ 31.75% offset  110 ⇔ 38.5% offset  111 ⇔ 43.25% offset  Note: Shift_method (bit 15 below) must be set to 1 to enable the offset shift.
	15	O <sub>BIN</sub>	Shift_method	Offset shift method selection:  0 ⇔ No offset shift, Offset (bits[14:12] in 12 <sub>HEX</sub> ) must be set to 000BIN, GainADC = 1  1 ⇔ Offset shift ADC, GainADC = 2
Post-Calibration	n Offset Correct	ion Coefficients	3	
17 <sub>HEX</sub>	15:0	0000 <sub>HEX</sub>	SENS_Shift[15:0]	Bits [15:0] of the post-calibration sensor offset shift coefficient SENS_Shift. (The MSB bits of SENS_Shift are bits [7:0] of register 19 <sub>HEX</sub> .)
18 <sub>HEX</sub>	15:0	0000 <sub>HEX</sub>	T_Shift[15:0]	Bits [15:0] of the post-calibration temperature offset shift coefficient T_Shift. (The MSB bits of T_Shift are bits [15:8] of register 19 <sub>HEX</sub> .)
40	7:0	00 <sub>HEX</sub>	SENS_Shift[23:16]	Bits [23:16] of the post-calibration sensor offset shift coefficient SENS_Shift. (The LSB bits of SENS_Shift are in register 17 <sub>HEX</sub> .)
19 <sub>HEX</sub>	15:8	00 <sub>HEX</sub>	T_Shift[23:16]	Bits [23:16] of the post-calibration temperature offset shift coefficient T_Shift. (The LSB bits of T_Shift are in register 18 <sub>HEX</sub> .)
Free Memory –	Arbitrary Use			
20 <sub>HEX</sub>	15:0	0000 <sub>HEX</sub>		Not assigned (e.g., can be used for Cust_IDx customer identification number)
21 <sub>HEX</sub>	15:0	0000 <sub>HEX</sub>		Not assigned (e.g., can be used for Cust_IDx customer identification number)



MTP Address	Word / Bit Range	Default Setting	Description	Notes / Explanations
37 <sub>HEX</sub>	15:0	0000 <sub>HEX</sub>		Not assigned (e.g., can be used for Cust_IDx customer identification number)
38 <sub>HEX</sub>	15:0	0000 <sub>HEX</sub>		Not assigned (e.g., can be used for Cust_IDx customer identification number)
39 <sub>HEX</sub>	15:0	-	Checksum	Checksum generated for whole memory through a linear feedback shift register (LFSR); signature is checked with power-up to ensure memory content integrity

The memory integrity checksum (referred to as CRC) is generated through a linear feedback shift register with the polynomial:

$$g(x) = x^{16} + x^{15} + x^2 + 1$$
 with the initialization value: FFFF<sub>HEX</sub>.

If the CRC is valid, then the "Memory Error" status bit is set to 0.



### 3.7 Calibration Sequence

Calibration essentially involves collecting raw signal and temperature data from the sensor-ZSSC3018 system for different known sensor-element values (i.e., a resistive bridge or an absolute voltage source) and temperatures. This raw data can then be processed by the calibration master (assumed to be the user's computer), and the calculated calibration coefficients can then be written to on-chip memory.

Here is a brief overview of the three main steps involved in calibrating the ZSSC3018.

Assigning a unique identification to the ZSSC3018. This identification is written to shadow RAM and programmed in MTP memory. This unique identification can be stored in the two 16-bit registers dedicated to the customer ID (00<sub>HEX</sub> and 01<sub>HEX</sub>; see Table 3.5). It can be used as an index into a database stored on the calibration computer. This database will contain all the raw values of the connected sensor-element readings and temperature readings for that part, as well as the known sensor-element measurand conditions and temperature to which the sensor-element was exposed.

Data collection. Data collection involves getting uncorrected or raw data from the external sensor at different known measurand values and temperatures. Then this data is stored on the calibration computer using the unique identification of the device as the index to the database.

Coefficient calculation and storage in MTP memory. After enough data points have been collected to calculate all the desired coefficients, the coefficients can be calculated by the calibrating computer. Then the coefficients can be programmed to the MTP memory.

Result. The sensor signal and the characteristic temperature effect on output will be linearized according to the setup-dependent maximum output range.

It is essential to perform the calibration with a fixed programming setup during the data collection phase. In order to prevent any accidental incorrect processing, it is further recommended that the MTP memory setup is kept stable during the whole calibration process as well as in the subsequent operation. A ZSSC3018 calibration only fits the setup used during its calibration. Changes of functional parameters after a successful calibration can decrease the precision and accuracy performance of the ZSSC3018 as well as of the whole application.

**Note:** The ZSSC3018 supports operation with different sensor setups via the  $SM\_config1$  and  $SM\_config2$  registers. However, only one calibration coefficient set is supported. Therefore, either an alternative ZSSC3218-external signal calibration using the alternate  $SM\_config$  settings must also be performed to ensure that the programmed SSC coefficients are valid for both setups, or a full reprogramming of the SSC coefficients must be performed each time the sensor setup is changed. The selection of the external sensor setup (i.e., the AFE configuration) can be done with the interface commands  $BO_{HEX}$  and  $BO_{HEX}$ .

#### 3.7.1 Calibration Step 1 - Assigning Unique Identification

Assign a unique identification number to the ZSSC3018 by using the memory write command (40<sub>HEX</sub> + data and 41<sub>HEX</sub> + data; see Table 3.1 and Table 3.5) to write the identification number to *Cust\_ID0* at memory address 00<sub>HEX</sub> and *Cust\_ID1* at address 01<sub>HEX</sub> as described in section 3.6.1. These two 16-bit registers allow for more than 4 billion unique devices.

#### 3.7.2 Calibration Step 2 - Data Collection

The number of unique points (measurand and/or temperature) at which calibration must be performed generally depends on the requirements of the application and the behavior of the sensor in use. The minimum number of points required is equal to the number of correction coefficients to be corrected with a minimum of three different temperatures at three different sensor values. For a full calibration resulting in values for all 7 possible (external) sensor coefficients and 3 possible temperature coefficients, a minimum of 7 pairs of sensor with temperature measurements must be collected.

Within this minimum field of 3 measurand measurements x 3 temperature measurements, data must be collected for the specific value pairs (at known conditions) and then processed to calculate the coefficients. In order to obtain the potentially best and most robust coefficients, it is recommended that measurement pairs (temperature vs. measurand) be collected at the outer corners of the intended operation range or at least at points that are located far apart. It is also essential to provide highly precise reference values as nominal, expected values. The measurement precision of the external calibration-measurement equipment should be ten times more accurate than the expected ZSSC3018 output accuracy after calibration in order to avoid accuracy losses caused by the nominal reference values (e.g., measurand signal and temperature deviations).

Note: The coefficients *SENS\_shift* and *T\_shift* must not be determined during this calibration step. Strong recommendation: Set these coefficients to zero until after initial calibration.



**Note**: An appropriate selection of measurement pairs can significantly improve the overall system performance.

The determination of the measurand-related coefficients will use all of the measurement pairs. For the temperature-related correction coefficients, 3 of the measurement pairs (at three different temperatures) will be used.

**Note:** There is an inherent redundancy in the 7 sensor-related and 3 temperature-related coefficients. Since the temperature is a necessary output (which also needs correction), the temperature-related information is mathematically separated, which supports faster and more efficient DSP calculations during the normal usage of the sensor-ZSSC3018 system. The recommended approach for data collection is to make use of the raw-measurement commands described in Table 3.2:

For external sensor values, either of the following commands can be used depending on the user's requirements:

- A2<sub>HEX</sub> + 0000<sub>HEX</sub>: Single sensor measurement for which the configuration register will be loaded from the SM\_config1 register (12<sub>HEX</sub> in MTP); preprogramming the measurement setup in the MTP is required.
  - Note:  $SM\_config1$  is the default configuration. Alternatively,  $SM\_config2$  (16<sub>HEX</sub> in MTP) can be used by first sending the command B1<sub>HEX</sub> (see section 3.7.5).
- A3<sub>HEX</sub> + ssss<sub>HEX</sub>: Single sensor measurement for which the *SM\_config* configuration register (Gain, ADC, Offset, etc.) will be loaded as the user's configuration ssss<sub>HEX</sub> and must be provided externally via the interface as the data part of this command.

For temperature values either of the following commands can be used depending on the user's requirements:

- A6<sub>HEX</sub> + 0000<sub>HEX</sub>: Single temperature measurement for which the configuration register will be loaded from an internal temperature configuration register (preprogrammed by Renesas in MTP); preprogramming of the respective configuration is done by Renesas prior to ZSSC3018 delivery. This is the recommended approach for temperature data collection.
- A7<sub>HEX</sub> + ssss<sub>HEX</sub>: Single temperature measurement for which the configuration register (Gain, ADC, Offset, etc.) will be loaded as ssss<sub>HEX</sub>, which must be provided externally via the interface as the data part of this command. In this case, the format and purpose of these configuration bits must be according to the definitions for *SM\_config* and valid for temperature measurement (bits [15:12] will be ignored).

#### 3.7.3 Calibration Step 3a) – Coefficient Calculations

The math to perform the coefficient calculation is complicated and will not be discussed in detail. There is a brief overview in the next section. Renesas will provide software (DLLs) to perform the coefficient calculation (external to the sensor-ZSSC3018 system) based on auto-zero corrected values. After the coefficients are calculated, the final step is to write them to the MTP memory of the ZSSC3018.

#### 3.7.4 Calibration Step 3b) - Post-Calibration Offset Correction

There are two special SSC-coefficients, *SENS\_shift* and *T\_shift*. Normally, these coefficients must be set to zero during the initial sensor calibration. The primary purpose of these two coefficients is to cancel additional offset shifts that could occur during or after final sensor assembly, e.g. if a respective sensor is finally placed and soldered on an application board.

If the final sensor assembly induced any kind of offset (on either the temperature or the external sensor signal), the respective influence can be directly compensated via the *SENS\_shift* and *T\_shift* coefficients without the need to change the original SSC coefficient set. However, this post-calibration offset correction must be done under known ambient conditions (i.e., sensor measurand and/or temperature).



#### 3.7.5 SSC Measurements

After the completion of the calibration procedure, linearized external sensor and temperature readings can be obtained using these commands: AA<sub>HEX</sub> to AF<sub>HEX</sub>.

Typically, only one external sensor in a single analog configuration (setup in *SM\_config1*, MTP register 12<sub>HEX</sub>) will be used. However, the ZSSC3018 can support a second analog configuration that is set up in *SM\_config2*, MTP register 16<sub>HEX</sub>. This might be useful in cases where only one sensor-ZSSC3218 pair must support the measurand ranges for two different external sensors that have different precisions, required amplification, and sensor offset.

If a respective switching between setups is to be performed, the SSC coefficients for the alternate external sensor must be handled with one of the following methods:

The programmed SSC coefficients are not used for the alternate external sensor. The ZSSC3218 performs only a one-to-one transfer, i.e. no effective digital SSC correction – only a transfer of the auto-zero corrected raw ADC readings to the ZSSC3218 output without any scaling, etc.

The coefficients are re-programmed each time the analog setup is changed.

 $SM\_config1$  is selected as analog setup register by default, so no specific activation is needed if only  $SM\_config1$  is used. If  $SM\_config2$  will also be used, the activation command  $B1_{HEX}$  must be sent once prior to the measurement requests. To switch to using  $SM\_config1$ , the activation command  $B0_{HEX}$  must be sent prior to use. This respective activation must be refreshed after any power-on-reset or RES pin reset.



#### 3.8 The Calibration Math

### 3.8.1 Bridge Signal Compensation

The saturation check in the ZSSC3018 detects saturation effects of the internal calculation steps, allowing the final correction output to still be determined. It is possible to get potentially useful signal conditioning results that have had an intermediate saturation during the calculations. These cases are detectable by observing the status bit[0] for each measurement result. Details about the saturation limits and the valid ranges for values are provided in the following equations.

The calibration math description assumes a calculation with integer numbers. The description is numerically correct concerning values, dynamic range, and resolution.

SOT\_curve selects whether second-order equations compensate for sensor nonlinearity with a parabolic or S-shaped curve. The parabolic compensation is recommended for most sensor types.

#### For the following equations, the terms are as follows:

S	Corrected sensor reading output via I <sup>2</sup> C or SPI; range [0 <sub>HEX</sub> to FFFFFF <sub>HEX</sub> ]
S_Raw	Raw sensor reading from ADC after AZ correction; range [-7FFF $_{\text{HEX}}$ , 7FFFF $_{\text{HEX}}$ ]
Gain_S	Sensor gain term; range [-7FFFFHEX, 7FFFFHEX]
Offset_S	Sensor offset term; range [-7FFFF <sub>HEX</sub> , 7FFFF <sub>HEX</sub> ]
Tcg	Temperature coefficient gain term; range [-7FFFFHEX, 7FFFFHEX]
Tco	Temperature coefficient offset term; range [-7FFFFHEX, 7FFFFHEX]
T_Raw	Raw temperature reading after AZ correction; range [-7FFFFHEX, 7FFFFHEX]
SOT_tcg	Second-order term for Tcg non-linearity; range [-7FFFF <sub>HEX</sub> , 7FFFF <sub>HEX</sub> ]
SOT_tco	Second-order term for Tco non-linearity; range [-7FFFF <sub>HEX</sub> , 7FFFF <sub>HEX</sub> ]
SOT_sens	Second-order term for sensor non-linearity; range [-7FFFF <sub>HEX</sub> , 7FFFF <sub>HEX</sub> ]
SENS_shift	Post-calibration, post-assembly sensor offset shift; range [-7FFFF $_{\text{HEX}}$ , 7FFFF $_{\text{HEX}}$ ]
	Absolute value

[...]<sup>ul</sup> Bound/saturation number range from ll to ul, over/under-flow is reported as saturation in the status byte The correction formula for the differential signal reading is represented as a two-step process depending on the  $SOT\_curve$  setting.

#### Equations for the parabolic *SOT\_curve* setting (*SOT\_curve* = 0):

Simplified:

$$K_{1} = 2^{23} + \frac{T - Raw}{2^{23}} * \left( \frac{4 * SOT - tcg}{2^{23}} * T - Raw + 4 * Tcg \right)$$
 (1)

$$K_2 = 4 * Offset_S + S_Raw + \frac{T_Raw}{2^{23}} * \left(\frac{4 * SOT_tco}{2^{23}} * T_Raw + 4 * Tco\right)$$
 (2)

$$Z_{SP} = \frac{4 * Gain\_S}{2^{23}} * \frac{K_1}{2^{23}} * K_2 + 2^{23} \qquad \text{(delimited to positive number range)}$$

$$S = \frac{Z_{BP}}{2^{23}} * \left( \frac{4 * SOT\_sens}{2^{23}} * Z_{SP} + 2^{23} \right) + SENS\_shift$$
 (delimited to positive number range)



Complete:

$$K_{1} = \left[ 2^{23} + \left[ \frac{T - Raw}{2^{23}} * \left[ \left[ \frac{SOT - tcg}{2^{21}} * T - Raw \right]_{-2^{25}}^{2^{25} - 1} + 4 * Tcg \right]_{-2^{25}}^{2^{25} - 1} \right]_{-2^{25}}^{2^{25} - 1} \right]_{-2^{25}}^{2^{25} - 1}$$
(5)

$$K_{2} = \left[ 4 * Offset\_S + \left[ S\_Raw + \left[ \frac{T\_Raw}{2^{23}} * \left[ \left[ \frac{SOT\_tco}{2^{21}} * T\_Raw \right]_{-2^{25}}^{2^{25}-1} + 4 * Tco \right]_{-2^{25}}^{2^{25}-1} \right]_{-2^{25}}^{2^{25}-1} \right]_{-2^{25}}^{2^{25}-1} \right]_{-2^{25}}^{2^{25}-1}$$

$$(6)$$

$$Z_{SP} = \left[ \frac{Gain_{S}}{2^{21}} * \left[ \frac{K_{1}}{2^{23}} * K_{2} \right]_{-2^{25}}^{2^{25}-1} + 2^{23} \right]_{-2^{25}}^{2^{25}-1}$$
 (7)

$$B = \left[ \frac{Z_{SP}}{2^{23}} * \left[ \left[ \frac{SOT\_sens}{2^{21}} * Z_{BP} \right]_{-2^{25}}^{2^{25}-1} + 2^{23} \right]_{-2^{25}}^{2^{25}-1} + SENS\_shift \right]_{0}^{2^{24}-1}$$
(8)

#### Equations for the S-shaped SOT curve setting (SOT curve = 1):

Simplified:

$$Z_{SS} = \frac{4 * Gain_{-}S}{2^{23}} * \frac{K_1}{2^{23}} * K_2$$
 (9)

$$S = \frac{Z_{SS}}{2^{23}} * \left( \frac{4 \cdot SOT\_sens}{2^{23}} * \left| Z_{SS} \right| + 2^{23} \right) + 2^{23} + SENS\_shift$$
 (delimited to positive number range) (10)

Complete:

$$Z_{SS} = \left[ \frac{Gain_{S}}{2^{21}} * \left[ \frac{K_{1}}{2^{23}} * K_{2} \right]_{-2^{25}}^{2^{25}-1} \right]_{-2^{25}}^{2^{25}-1}$$
(11)

$$S = \left[ \left[ \frac{Z_{SS}}{2^{23}} * \left[ \left[ \frac{SOT\_sens}{2^{21}} * |Z_{SS}| \right]_{-2^{25}}^{2^{25}-1} + 2^{23} \right]_{-2^{25}}^{2^{25}-1} + 2^{23} + SENS\_shift \right]_{0}^{2^{24}-1}$$

$$(12)$$



### 3.8.2 Temperature Signal Compensation

Temperature is measured internally. Temperature correction contains both linear gain and offset terms as well as a second-order term to correct for any nonlinearities. For temperature, second-order compensation for nonlinearity is always parabolic.

The correction formula is best represented as a two-step process as follows:

Simplified:

$$Z_{T} = \frac{4 * Gain \_T}{2^{23}} * (T \_Raw + 4 * Offset \_T) + 2^{23}$$
 (delimited to positive number range) (13)

$$T = \frac{Z_T}{2^{23}} * \left( \frac{4 * SOT_T}{2^{23}} * Z_T + 2^{23} \right) + T_Shift \qquad \text{(delimited to positive number range)}$$

Complete:

$$Z_{T} = \left[ \left[ \frac{Gain\_T}{2^{21}} * \left[ T\_Raw + 4Offset\_T \right]_{-2^{25}}^{2^{25}-1} \right]_{-2^{25}}^{2^{25}-1} + 2^{23} \right]_{0}^{2^{25}-1}$$
(15)

$$T = \left[ \frac{Z_{T}}{2^{23}} * \left[ \left[ \frac{SOT_{T}}{2^{21}} * Z_{T} \right]_{-2^{25}}^{2^{25}-1} + 2^{23} \right]_{-2^{25}}^{2^{25}-1} + T_{Shift} \right]_{0}^{2^{24}-1}$$
(16)

#### Where

Τ	Corrected temperature sensor reading output via I <sup>2</sup> C or SPI; range [0 <sub>HEX</sub> to FFFFF <sub>HEX</sub> ]
Gain_T	Gain coefficient for temperature; range [-7FFFFF <sub>HEX</sub> to 7FFFFF <sub>HEX</sub> ]
T_Raw	Raw temperature reading after AZ correction; range [-7FFFFF <sub>HEX</sub> to 7FFFFF <sub>HEX</sub> ]
Offset_T	Offset coefficient for temperature; range [-7FFFFF <sub>HEX</sub> to 7FFFFF <sub>HEX</sub> ]
SOT_T	Second-order term for temperature source non-linearity; range [-7FFFFHEX to 7FFFFHEX]
T Shift	Shift for post-calibration/post-assembly offset compensation; range I-7FFFFHEX to 7FFFFHEX



### 3.8.3 Measurement Output Data Format

The data format and bit assignment of the raw measurement and SSC-corrected outputs of the ZSSC3018 are defined in the following tables. Any ADC measurement and SSC calculation output is formatted as a 24-bit wide data word, regardless on the effective ADC resolution used. The values are either in two's complement or sign-absolute format.

Table 3.6 Measurement Results of ADC Raw Measurement Request (Two's Complement)

Bit	23	22	21	20	 1	0
Meaning, Weighting	-20	2-1	2-2	2 <sup>-3</sup>	 2-22	2-23

## Table 3.7 Calibration Coefficients (Factors and Summands) in Memory (Sign-Magnitude)

Bit	23	22	21	20	 1	0
Meaning, weighting	0=positive 1=negative	21	20	2-1	 2-20	2-21

#### Table 3.8 Output Results from SSC-Correction Math or DSP—Sensor and Temperature

Bit	23	22	21	20	 1	0
Meaning, weighting	20	2-1	2-2	2-3	 2-22	2-23

#### Table 3.9 Interrupt Thresholds TRSH1 and TRSH2—Format as for SSC-Correction Math Output

Bit	23	22	21	20	 1	0
Meaning, weighting	20	2-1	2-2	2-3	 2-22	2-23



# 4. Packaging Dimensions and Pin Assignments

The ZSSC3018 is available as die or as a 24-PQFN. See Table 4.1 for detailed 24-PQFN package dimensions and Table 4.2 for pin descriptions.

For die and pad dimensions refer to the ZSSC3018 Technical Brief – Die and Pad Dimensions.

Figure 4.1 General 24-PQFN Package Dimensions

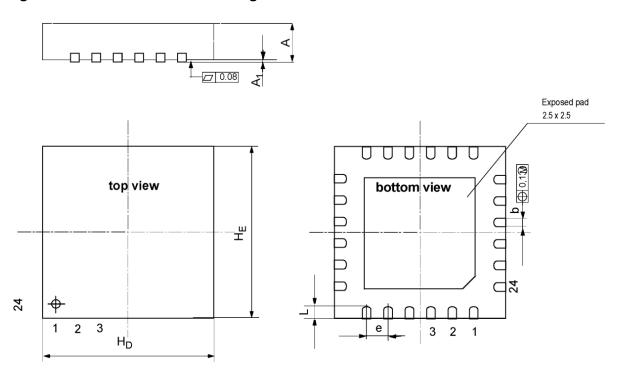


Table 4.1 24-PQFN Dimensions (4 x 4 mm)

Dimension Limit	MIN	NOM	MAX
А	0.80		0.90
A <sub>1</sub>	0.00		0.05
b	0.20		0.30
е		0.50	
H <sub>D</sub>	3.90		4.10
H <sub>E</sub>	3.90		4.10
L	0.30		0.50



### Table 4.2 Pin Assignments 24-PQFN

Note: In the following table, "n.c." stands for not connected / no connection required / not bonded.

Pin No.	Name	Direction	Туре	Description
1	TEST1	-	-	Do not connect.
2	RES	In	Digital	ZSSC3018 reset (low active, internal pull-up).
3	VDDB	Out	Analog	Positive external bridge-sensor supply.
4	INN	ln	Analog	Negative sensor signal (or sensor ground for absolute voltage-source sensors).
5	EOC	Out	Digital	End of conversion or interrupt output.
6	MISO	Out	Digital	Data output for SPI.
7	TEST2	-	_	Do not connect.
8	n.c.	-	-	-
9	n.c.	-	-	-
10	n.c.	-	-	-
11	n.c.	-	-	-
12	SCLK/SCL	In	Digital	Clock input for SPI/I <sup>2</sup> C.
13	MOSI/SDA	In/Out	Digital	Data input for SPI; data in/out for I <sup>2</sup> C.
14	VSSB	Out	Analog	Negative external bridge-sensor supply (sensor ground).
15	INP	In	Analog	Positive sensor signal.
16	TEST5	-	-	Do not connect.
17	SS	In	Digital	Slave select for SPI.
18	TEST4	-	-	Do not connect.
19	TEST3	-	_	Do not connect.
20	n.c.	-	-	-
21	n.c.	-	-	-
22	VDD	In	Supply	IC positive supply voltage for the ZSSC3018.
23	n.c.	-	-	-
24	VSS	In	Supply	Ground reference voltage signal.
25	Exposed pad	-	_	Do not connect electrically.



# 5. Quality and Reliability

The ZSSC3018 is available as a qualified IC version for consumer and industrial market applications. All data specified parameters are guaranteed if not stated otherwise.

# 6. Ordering Information

Product Sales Code	Description	Package
ZSSC3018BA3W	ZSSC3018 24-PQFN – temperature range: –40°C to +125°C	7" Reel
ZSSC3018BA1B	ZSSC3018 Die – temperature range: –40°C to +125°C	Unsawn on Wafer (304µm)
ZSSC3018BA2B	ZSSC3018 Die – temperature range: –40°C to +125°C	Unsawn on Wafer (725µm)
ZSSC3018BA2C	ZSSC3018 Die – temperature range: –40°C to +125°C	Sawn on Wafer Frame
ZSSC3018BA2D	ZSSC3018 Die – temperature range: –40°C to +125°C	Sawn in Waffle Pack (for sampling only)
ZSSC3018KITV1P0	Modular ZSSC3018 SSC Evaluation Kit including three interconn samples, and cable. Software is available for download on www.l	

### 7. Related Documents

Visit the ZSSC3018 product page at <a href="https://www.IDT.com/ZSSC3018">www.IDT.com/ZSSC3018</a> or contact your nearest sales office for ordering information or the latest version of this document and related documents.

# 8. Glossary

Term	Description			
A2D	Analog-to-Digital			
ACK	Acknowledge (interface's protocol indicator for successful data/command transfer)			
ADC	Analog-to-Digital Converter or Conversion			
ALU	Arithmetic Logic Unit			
AZ	Auto-Zero (unspecific)			
AZSM	Auto-Zero Measurement for (external) Sensor Path			
AZTM	Auto-Zero Measurement for Temperature Path			
Au	Gold			
CLK	Clock			
Cu	Copper			
DAC	Digital-to-Analog Conversion or Converter			
DF	Data Fetch (command type)			
DSP	Digital Signal Processor (digital configuration, calibration, calculation, communication unit)			



Term	Description
EOC	End of Conversion
FSO	Full Scale Output (value in percent relative to the ADC maximum output code; resolution dependent)
LSB	Least Significant Bit
LFSR	Linear Feedback Shift Register
MR	Measurement Request (command type)
MSB	Most Significant Bit
MTP	Multiple-Time Programmable Memory
NACK	Not Acknowledge (interface's protocol indicator for unsuccessful data/command transfer)
POR	Power-on Reset
PreAmp	Preamplifier
PSRR	Power Supply Disturbance Rejection Ratio
SM	Signal Measurement
SOT	Second-Order Term
TC	Temperature Coefficient (of a resistor or the equivalent bridge resistance)
TM	Temperature Measurement



# 9. Revision History

Date	Description
September 8, 2020	Update for order codes in section 6.
	Changed to Renesas branding
January 10, 2017	Updates for product sales codes and addition of new product sales code for die samples in waffle pack.
November 14, 2016	Correction for typical sensor system accuracy specification on page 1 and in Table 1.4 from ±0.01% FSO to ±0.10% FSO.
	Addition of die as a delivery option.
	Revision of name for ZMDI-test pins in Table 4.2.
	Updates for formatting for text and figures.
July 18, 2016	Correction for package dimensions in section 4.
January 26, 2016	Changed to IDT branding. Revision reference is now the document release date.
December 10, 2015	Update for order codes in section 6.
(Rev. 1.01)	Correction for Figure 3.12.
	Minor edits for clarity.
November 12, 2015	First release.
(Rev. 1.00)	

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